

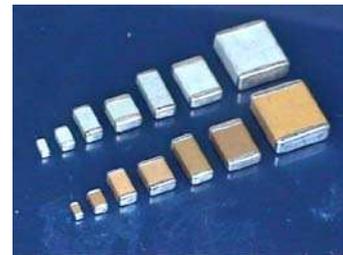
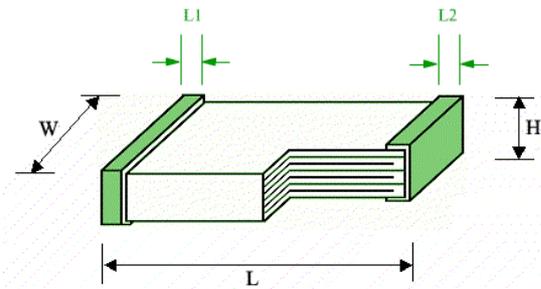
### Multilayer Ceramic Chip Capacitors

Middle & high voltage MLCC is a kind of special design , special technology MLCC that bases on the technology of general MLCC. This kind of MLCC has stable high voltage reliability and suitable to SMT. Middle & high MLCC is widely applicable for many direct high voltage circuits in which it can improve the performance of the circuit.

### Features

- Series size from 0603~2225
- Working Voltage from 100V~5000V
- Surface mount suited for wave and reflow soldering
- Wide Operating temperature range from -55°C-125°C
- Good Temperature Coefficient
- High reliability

### Dimension



### How To Order

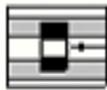
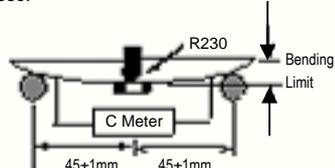
HV	1206	X7R	102	K	202	P
Product Code	Size	Dielectric	Capacitance	Tolerance	Rated Voltage	Termination
	Ex.: 0603	Ex.: COG=NPO	Unit : pF	Ex.: A=±0. 1pF	Ex.: 6R3=6. 6V	P:Ag/Ni/Sn
HV=High	0805	X7R	Ex.: 0R5=0. 5pF	B=±0. 2pF	500=50V	S:Ag/Pd/Pt
Voltage	1206	X5R	2R5=2. 5pF	C=±0. 25pF	102=1000V	
Capacitance	1210	Y5V	102=10×10 <sup>2</sup>	D=±0. 5pF	202=2000V	
HA=Safety	1808	Z5U	684=68×10 <sup>4</sup>	F=±1%	502=5000V	
Capacitors	1812			G=±2%		
HC=High	2220			J=±5%		
Capacitance	2225			K=±10%		
				M=±20%		
				Z=+80%/-20%		

### Capacitance Range

Size Inch (mm)	L	W	H (MAX)	Rated Voltage	Capacitance Range (PF)	
					COG/NPO	X7R
0603 (1608)	1.60±	0.80±	0.8	100V	1~470 (471)	150~18000 (183)
	0.20	0.20		200V	1~150 (151)	150~6800 (682)
0805 (2012)	2.0±	1.25±	1.3	100V	1~1000 (102)	150~100000 (104)
	0.2	0.2		200V/250V	1~680 (681)	150~22000 (223)
				500V	1~560 (561)	150~10000 (103)
1206 (3216)	3.2±	1.6±	1.6	100V	5~4700 (472)	150~4740000 (474)
	0.3	0.2		200V/250V	5~2700 (272)	150~100000 (104)
				500V	5~1500 (152)	150~47000 (563)
				1000V	5~820 (821)	150~10000 (103)
				2000V	5~390 (391)	150~2200 (222)
				2500V	—————	150~1000 (102)
1210 (3225)	3.2±	2.5±	2.0	100V	10~10000 (103)	150~1000000 (105)
	0.3	0.3		250V	10~4700 (472)	150~220000 (224)
				500V	10~3300 (332)	150~68000 (683)
				1000V	10~1000 (102)	150~22000 (223)
				2000V	10~560 (561)	150~6800 (682)
1808 (4520)	4.5±	2.0±	2.0	1000V	2~1000 (102)	150~15000 (153)
	0.35	0.3		2000V	2~330 (331)	150~2200 (222)
				3000V	2~270 (271)	150~1800 (182)
				5000V	2~100 (101)	—————
1812 (4532)	4.5±	3.2±	2.8	100V	—————	10000~2200000 (225)
	0.35	0.3		250V	10~10000 (103)	10000~1000000 (105)
				500V/630V	10~6800 (682)	1000~470000 (474)
				1000V	10~5600 (562)	1000~47000 (473)
				2000V	10~1000 (102)	150~10000 (103)
				3000V	10~680 (681)	150~4700 (472)
				4000V	10~100 (101)	150~1000 (102)
2220 (5750)  2225 (5763)	5.7±	5.0±	3.5	100V	—————	470000~4700000 (475)
	0.4	0.4		250V	100~33000 (333)	10000~2200000 (225)
				500V/630V	100~15000 (153)	10000~470000 (474)
				1000V	100~10000 (103)	10000~220000 (224)
				2000V	100~1500 (152)	1000~33000 (333)
				3000V	100~1000 (102)	150~10000 (103)
				4000V	100~680 (681)	150~3900 (392)
				5000V	100~470 (471)	150~2200 (222)
5.7±	6.3±	0.4	—————	—————	—————	

※ We can design according to customer special requirements.

### HV Series Specification & Test Condition

Item	Specification	Test Condition									
<b>Operation Temperature</b>	-55 to +125°C										
<b>Visual</b>	No abnormal exterior appearance	Visual Inspection									
<b>Capacitance</b>	Within The Specified Tolerance	Class      Frequency      Voltage									
<b>Quality Factor</b>	Class I (NPO): More Than 30pF : Q ≧ 1000 30pF & Below: Q ≧ 400+20C (C:Cap., pF)	NPO C≤100pF      1MHz±10%      1.0±0.2Vrms C>100pF      1KHz±10%									
		X7R      1KHz±10%      1.0±0.2Vrms									
<b>Dissipation Factor</b>	Class II (X7R): Maximum 0.025	Perform a heat temperature at 150±5°C for 30min. then place room temp. for 24±2hr.									
<b>Insulation Resistance</b>	10,000MΩ or 500/C Ω whichever is smaller. (C in Farad)	V ≧ 500V, Rated Voltage V > 500V, Applied 500Vdc Charge Time : 60sec. Is applied less than 50mA current.									
<b>Withstanding Voltage</b>	No dielectric breakdown or mechanical breakdown	200V ≧ V < 500V : 200% Rated Voltage 500V ≧ V < 1000V: 150% Rated Voltage 1000 ≧ V : 120% Rated Voltage for 1~5 sec. Current is limited to less than 50mA.  Withstanding voltage testing requires immersion of the element in a isolation fluid prevent arcing on the chip surface, at voltage over 1000Vdc.									
<b>Temperature Capacitance Coefficient</b>	<table border="1"> <thead> <tr> <th>Char.</th> <th>Temp. Range</th> <th>Cap. Change</th> </tr> </thead> <tbody> <tr> <td>NPO(N)</td> <td>-55°C~ +125°C</td> <td>± 30ppm/°C</td> </tr> <tr> <td>X7R (X)</td> <td>-55°C~ +125°C</td> <td>± 15%</td> </tr> </tbody> </table>	Char.	Temp. Range	Cap. Change	NPO(N)	-55°C~ +125°C	± 30ppm/°C	X7R (X)	-55°C~ +125°C	± 15%	Class I: $[C2-C1/C1(T2-T1)] \times 100\%$ Class II : $(C2-C1)/C1 \times 100\%$ T1:Standard Temperature(25°C) T2:Test Temperature C1:Capacitance At Standard Temperature C2:Capacitance At Test Temperature
Char.	Temp. Range	Cap. Change									
NPO(N)	-55°C~ +125°C	± 30ppm/°C									
X7R (X)	-55°C~ +125°C	± 15%									
<b>Adhesive Strength of Termination</b>	No indication of peeling shall occur on the terminal electrode.	 5N · f      A 5N · f(=0.5Kg · f) pull force shall be applied for 10±1 sec.									
<b>Resistance to Flexure of Substrate</b>	No mechanical damage or capacitance change more than the following table.	The board shall be bend 1.0mm with a rate of 1.0 mm/sec.									
	<table border="1"> <thead> <tr> <th>Char.</th> <th>Capacitance Change</th> </tr> </thead> <tbody> <tr> <td>NPO(N)</td> <td>≧ ± 5.0% of initial value</td> </tr> <tr> <td>X7R (X)</td> <td>≧ ± 12.5% of initial value</td> </tr> </tbody> </table>	Char.	Capacitance Change	NPO(N)	≧ ± 5.0% of initial value	X7R (X)	≧ ± 12.5% of initial value				
Char.	Capacitance Change										
NPO(N)	≧ ± 5.0% of initial value										
X7R (X)	≧ ± 12.5% of initial value										
<b>Solderability</b>	More than 90% of the terminal surface is to be soldered newly, so metal part does not come out or dissolve .	Solder Temperature : 245±5°C Dip Time : 5 ± 0.5 sec. Immersing Speed : 25±10% mm/s Solder : H63A Flux :Rosin Preheat : At 80~120 °C For 10~30sec.									
											

## Multilayer Ceramic Chip Capacitors

### HV Series Specification & Test Condition

Item	Specification	Test Condition															
<b>Resistance to Soldering Heat</b>	Appearance	No mechanical damage shall occur															
	Capacitance	Class I (NPO): Within 2.5% or $\pm 0.25\text{pF}$ whichever is larger of initial value Class II (X7R): Within $\pm 10\%$ of initial value															
	Q / Tan $\delta$	To satisfy the specified initial value															
	Insulation Resistance	To satisfy the specified initial value															
		Class II capacitor shall be set for $48 \pm 4$ hours at room temperature after one hour heat treatment at $150 \pm 0/-10^\circ\text{C}$ before initial measure.  Preheat : at $150 \pm 10^\circ\text{C}$ for 60~120sec. Dip : solder temperature of $260 \pm 5^\circ\text{C}$ Dip Time : $10 \pm 1$ sec. Immersing Speed : $25 \pm 10\%$ mm/s Solder : H63A Flux : Rosin															
		Measure at room temperature after cooling for Class I : $24 \pm 2$ Hours Class II : $48 \pm 4$ Hours															
<b>Temperature Cycle</b>	Appearance	No mechanical damage shall occur															
	Capacitance	Class I (NPO): Within 2.5% or $\pm 0.25\text{pF}$ whichever is larger of initial value Class II (X7R): Within $\pm 7.5\%$ of initial value															
	Q / Tan $\delta$	To satisfy the specified initial value															
	Insulation Resistance	To satisfy the specified initial value															
		Class II capacitor shall be set for $48 \pm 4$ hours at room temperature after one hour heat treatment at $150 \pm 0/-10^\circ\text{C}$ before initial measure. Capacitor shall be subjected to five cycles of the temperature cycle as following:															
		<table border="1"> <thead> <tr> <th>Step</th> <th>Temp.(<math>^\circ\text{C}</math>)</th> <th>Time(min)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>Min Rated Temp.+0/-3 (-55)</td> <td>30</td> </tr> <tr> <td>2</td> <td>25</td> <td>3</td> </tr> <tr> <td>3</td> <td>Max Rated Temp.+3/-0 (125)</td> <td>30</td> </tr> <tr> <td>4</td> <td>25</td> <td>3</td> </tr> </tbody> </table>	Step	Temp.( $^\circ\text{C}$ )	Time(min)	1	Min Rated Temp.+0/-3 (-55)	30	2	25	3	3	Max Rated Temp.+3/-0 (125)	30	4	25	3
Step	Temp.( $^\circ\text{C}$ )	Time(min)															
1	Min Rated Temp.+0/-3 (-55)	30															
2	25	3															
3	Max Rated Temp.+3/-0 (125)	30															
4	25	3															
		Measure at room temperature after cooling for Class I : $24 \pm 2$ Hours Class II : $48 \pm 4$ Hours															
<b>Humidity</b>	Appearance	No mechanical damage shall occur															
	Capacitance	Class I (NPO): Within 5% or $\pm 0.5\text{pF}$ whichever is larger of initial value Class II (X7R): Within $\pm 15\%$ of initial value															
	Q / Tan $\delta$	Class I (NPO): More Than 30pF : $Q \geq 350$ 30pF & Below: $Q \geq 275 + 2.5C$ Class II (X7R): Maximum $\pm 5.0\%$															
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)															
		Class II capacitor shall be set for $48 \pm 4$ hours at room temperature after one hour heat treatment at $150 \pm 0/-10^\circ\text{C}$ before initial measure.  Temperature : $40 \pm 2^\circ\text{C}$ Relative Humidity : 90 ~95%RH Test Time : 500 $\pm 12/-0$ hr															
		Measure at room temperature after cooling for Class I : $24 \pm 2$ Hours Class II : $48 \pm 4$ Hours															

### HV Series Specification & Test Condition

Item	Specification	Test Condition								
<b>High Temperature Load (Life Test)</b>	Appearance	No mechanical damage shall occur								
	Capacitance	Class I (NPO): Within 3% or $\pm 0.3\text{pF}$ whichever is larger of initial value Class II (X7R): Within $\pm 15\%$ of initial value								
	Q / Tan $\delta$	Class I (NPO): More Than 30pF : Q $\geq 350$ 30pF & Below: Q $\geq 275 + 2.5C$ Class II (X7R): Maximum $\pm 5\%$								
	Insulation Resistance	1,000M $\Omega$ or 50/C $\Omega$ whichever is smaller. (C in Farad)								
		Class II capacitors applied DC voltage (following table) is applied for one hour at maximum operation temperature $\pm 3^\circ\text{C}$ then shall be set for 48 $\pm 4$ hours at room temperature and the initial measurement shall be conducted. Applied Voltage : <table border="1" style="margin-left: 20px;"> <thead> <tr> <th>Rated Voltage</th> <th>Applied Voltage</th> </tr> </thead> <tbody> <tr> <td><math>\leq 250\text{Vdc}</math></td> <td>150% Rated Voltage</td> </tr> <tr> <td><math>&gt; 250\text{Vdc} &lt; 1\text{KVdc}</math></td> <td>120% Rated Voltage</td> </tr> <tr> <td><math>\geq 1\text{KVdc}</math></td> <td>100% Rated Voltage</td> </tr> </tbody> </table>	Rated Voltage	Applied Voltage	$\leq 250\text{Vdc}$	150% Rated Voltage	$> 250\text{Vdc} < 1\text{KVdc}$	120% Rated Voltage	$\geq 1\text{KVdc}$	100% Rated Voltage
Rated Voltage	Applied Voltage									
$\leq 250\text{Vdc}$	150% Rated Voltage									
$> 250\text{Vdc} < 1\text{KVdc}$	120% Rated Voltage									
$\geq 1\text{KVdc}$	100% Rated Voltage									
		Temperature : max. operation temperature Test Time : 1000 +12/-0Hr Current Applied : 50 mA Max. Measure at room temperature after cooling for Class I : 24 $\pm$ 2 Hours Class II : 48 $\pm$ 4 Hours								
<b>Vibration</b>	Appearance	No mechanical damage shall occur								
	Capacitance	Within the specified tolerance								
	Q / Tan $\delta$	To satisfy the specified initial value								
		Solder the capacitor on P.C. board. Vibrate the capacitor with amplitude of 1.5mm P-P changing the frequencies from 10Hz to 55Hz and back to 10Hz in about 1 min. Repeat this for 2 hours each in 3 perpendicular directions.								